

Vishay Siliconix

P-Channel 60-V (D-S) 175° MOSFET

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

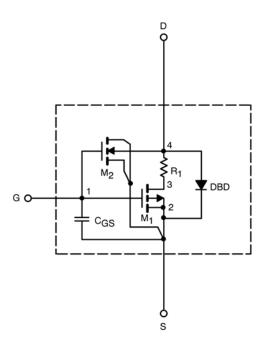
- Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125° C temperature ranges under the pulsed 0-V to 10-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

SUBCIRCUIT MODEL SCHEMATIC

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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SPICE Device Model SUP90P06-09L **Vishay Siliconix**



SPECIFICATIONS (T _J = 25°C UN	LESS OTHERW	'ISE NOTED)			
Parameter	Symbol	Test Condition	Simulated Data	Measured Data	Unit
Static		•	-		
Gate Threshold Voltage	V _{GS(th)}	V_{DS} = V_{GS} , I_D = $-250 \ \mu A$	2.1		V
On-State Drain Current ^a	I _{D(on)}	V_{DS} = -5 V, V_{GS} = -10 V	644		А
Drain-Source On-State Resistance ^a	r _{DS(on)}	V_{GS} = -10 V, I _D = -30 A	0.0074	0.0074	Ω
		V_{GS} = -10V, I_{D} = -30 A, T_{J} = 125°C	0.0116		
		V_{GS} = -10V, I_{D} = -30 A, T_{J} = 175°C	0.0139		
		V_{GS} = -4.5 V, I _D = -20 A	0.0092	0.0094	
Forward Transconductance ^a	g _{fs}	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -30 \text{ A}$	76		S
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S}$ = -50 A, $V_{\rm GS}$ = 0 V	-0.91	-1	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = -25 V, f = 1 MHz	8417	9200	pF
Output Capacitance	C _{oss}		970	975	
Reverse Transfer Capacitance	C _{rss}		801	760	
Total Gate Charge ^c	Qg	V_{DS} = -30 V, V_{GS} = -10 V, I_D = -90 A	176	160	nC
Gate-Source Charge ^c	Q _{gs}		40	40	
Gate-Drain Charge ^c	Q _{gd}		36	36	
Turn-On Delay Time ^c	t _{d(on)}	V_{DD} = -30 V, R _L = 0.33 Ω I _D \cong -90 A, V _{GEN} = -10 V, R _G = 2.5 Ω	13	20	ns
Rise Time ^c	tr		255	190	
Turn-Off Delay Time ^c	t _{d(off)}		102	140	
Fall Time ^c	t _f		352	300	

Notes

a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2%. b. Guaranteed by design, not subject to production testing. c. Independent of operating temperature.



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5.0 5.5

120

20

16

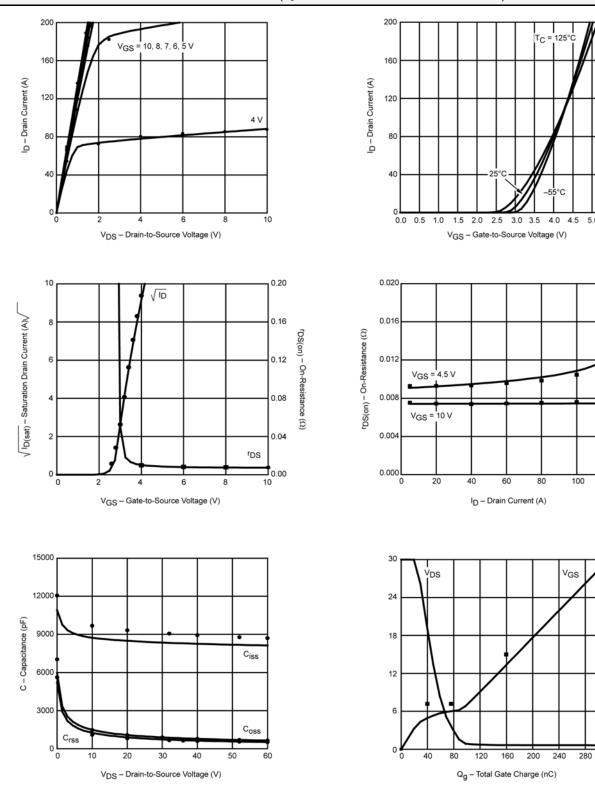
12

8

4

320

COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)



Note: Dots and squares represent measured data

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